



TSH321

WIDE BANDWIDTH AND MOS INPUTS SINGLE OPERATIONAL AMPLIFIER

- LOW DISTORTION
- GAIN BANDWIDTH PRODUCT : 300MHz
- GAIN OF 2 STABILITY
- SLEW RATE : 400V/ μ s
- VERY FAST SETTTLING TIME : 60ns (0.1%)
- VERY HIGH INPUT IMPEDANCE

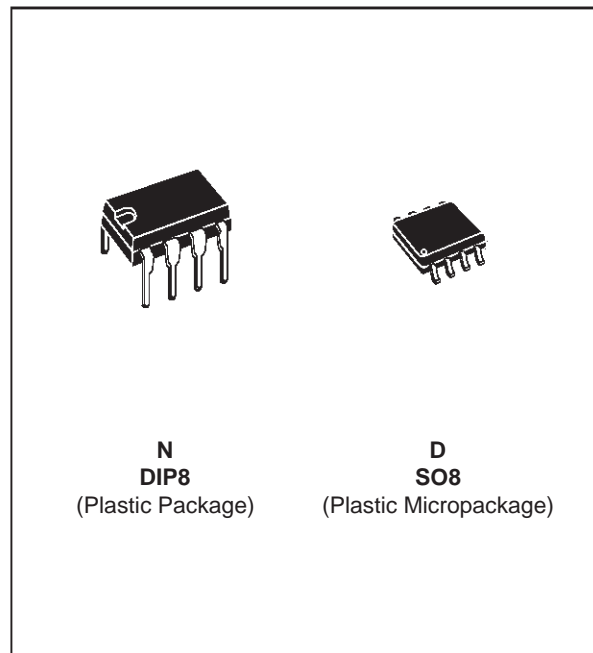
DESCRIPTION:

The TSH321 is a wideband monolithic operational amplifier, requiring a minimum close loop gain of 2 for stability.

The TSH321 features extremely high input impedance (typically greater than $10^{12}\Omega$) allowing direct interfacing with high impedance sources.

Low distortion, wide bandwidth and high linearity make this amplifier suitable for RF and video applications. Short circuit protection is provided by an internal current-limiting circuit.

The TSH321 has internal electrostatic discharge (ESD) protection circuits and fulfills MILSTD883C-Class2.

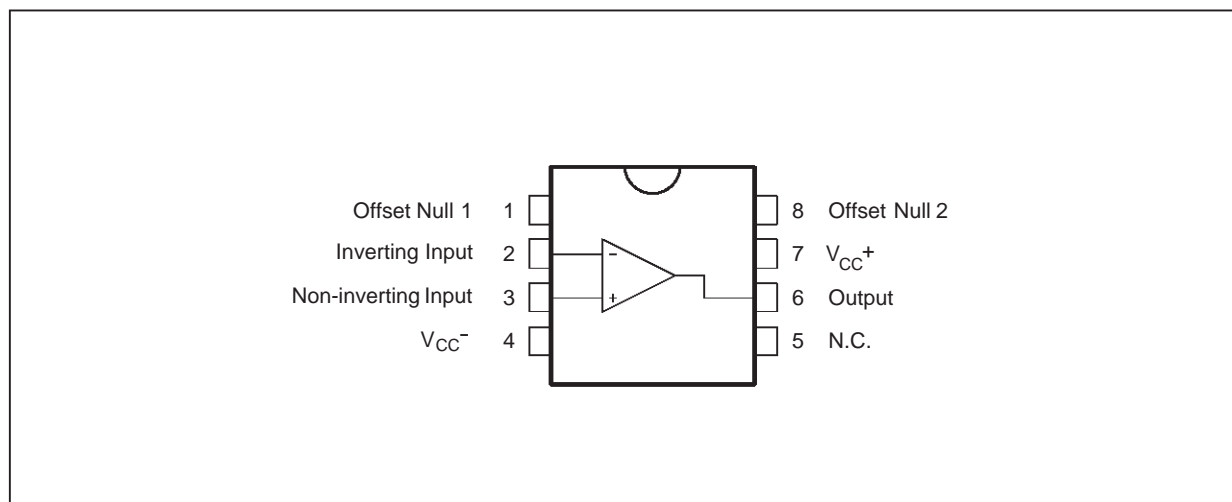


ORDER CODES

| Part Number | Temperature Range | Package | |
|-------------|-------------------|---------|---|
| | | N | D |
| TSH321I | -40°C, 125°C | • | • |

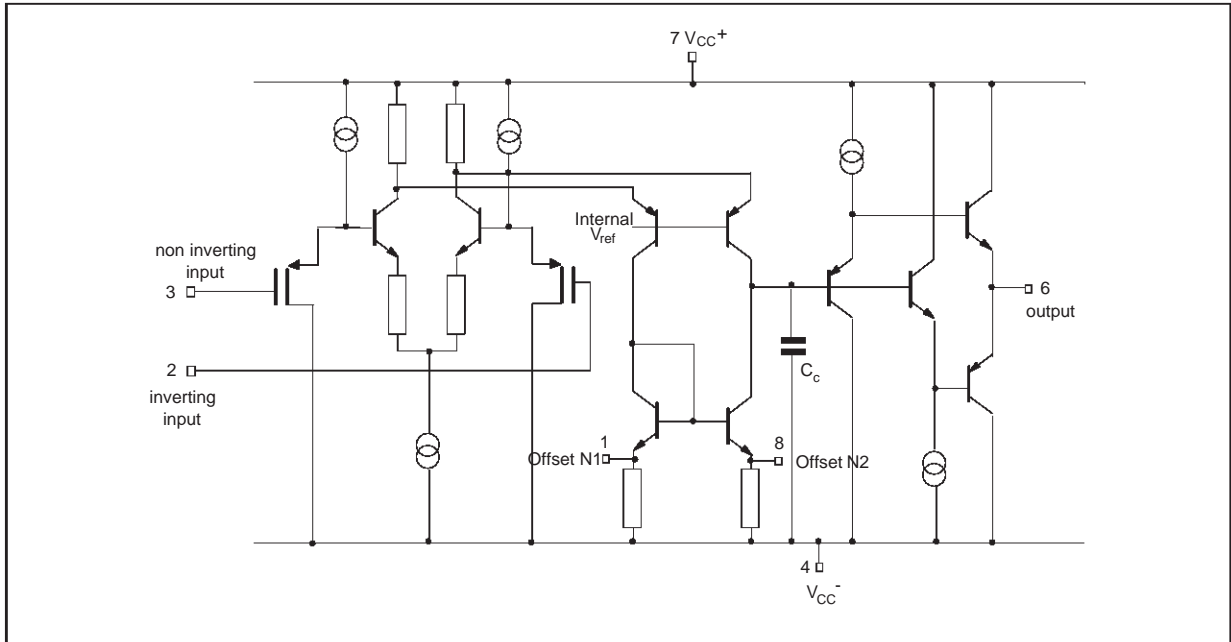
321-01.TBL

PIN CONNECTIONS (top view)



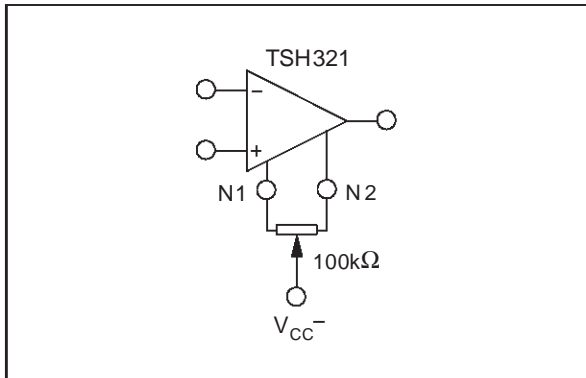
321-01.EPS

SCHEMATIC DIAGRAM



321-02.EPS

INPUT OFFSET VOLTAGE NULL CIRCUIT



321-03.EPS

ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|------------|--------------------------------------|---|--------------------|
| V_{CC} | Supply Voltage | ± 7 | V |
| V_{id} | Differential Input Voltage | ± 5 | V |
| V_i | Input Voltage Range | ± 5 | V |
| I_{in} | Current On Offset Null Pins | ± 20 | mA |
| T_{oper} | Operating Free-Air Temperature Range | TSH321I $-40^{\circ}\text{C}, 125^{\circ}\text{C}$ | $^{\circ}\text{C}$ |

321-03.TBL

OPERATING CONDITIONS

| Symbol | Parameter | Value | Unit |
|----------|---------------------------------|----------------------------|------|
| V_{CC} | Supply Voltage | ± 3 to ± 6 | V |
| V_{ic} | Common Mode Input Voltage Range | V_{CC-} to $V_{CC+} - 3$ | V |

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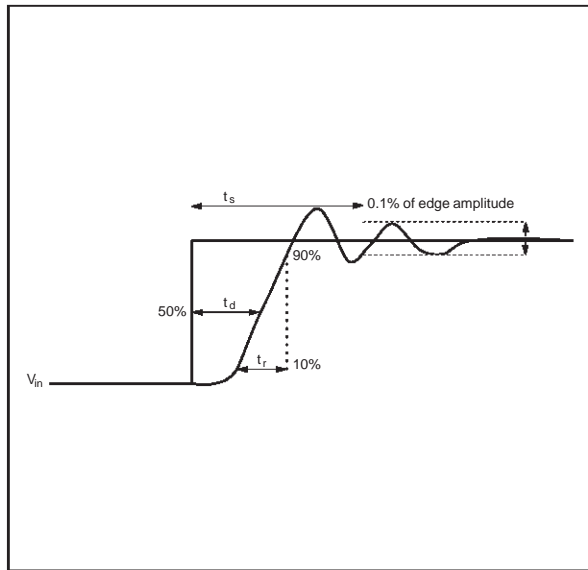
ELECTRICAL CHARACTERISTICSV_{CC} = ± 5V, T_{amb} = 25°C (unless otherwise specified)

| Symbol | Parameter | Min. | Typ. | Max. | Unit |
|---------------------------------|---|--------------------------------|--|----------------------|------------------------|
| V _{io} | Input Offset Voltage T _{min} ≤ T _{amb} ≤ T _{max} . | | 0.5 | 10 12 | mV |
| DV _{io} | Input Offset Voltage Drift T _{min} ≤ T _{amb} ≤ T _{max} . | | 10 | | μV/°C |
| I _{ib} | Input Bias Current | | 2 | 300 | pA |
| I _{io} | Input Offset Current | | 2 | 200 | pA |
| I _{CC} | Supply Current, no load T _{min} ≤ T _{amb} ≤ T _{max} . | | V _{CC} = ± 5V 23 V _{CC} = ± 3V 21 V _{CC} = ± 6V 25 V _{CC} = ± 5V 32 | 30 28 40 32 | mA |
| A _{vd} | Large Signal Voltage Gain V _o = ±2.5V | | | | V/V |
| | R _L = ∞ R _L = 100Ω R _L = 50Ω | 800 300 200 | 1300 850 650 | | |
| V _{icm} | Input Common Mode Voltage Range | -5 to +2 | -5.5 to +2.5 | | V |
| CMR | Common Mode Rejection Ratio V _{ic} = V _{icm min.} | 60 | 100 | | dB |
| SVR | Supply Voltage Rejection Ratio V _{CC} = ± 5V to ± 3V | 50 | 70 | | dB |
| V _o | Output Voltage T _{min} ≤ T _{amb} ≤ T _{max} . | | | | V |
| | R _L = 100Ω R _L = 50Ω R _L = 100Ω R _L = 50Ω | ± 3 ± 2.8 ± 2.9 ± 2.7 | +3.5 -3.7 +3.3 -3.5 | | |
| I _o | Output Short Circuit Current V _{id} = ±1V, V _o = 0V | ± 50 | ± 100 | | mA |
| GBP | Gain Bandwidth Product A _{VCL} = 100, R _L = 100Ω, C _L = 15pF, f = 7.5MHz | | 300 | | MHz |
| SR | Slew Rate V _{in} = ± 1V, A _{VCL} = 2, R _L = 100Ω, C _L = 15pF | 200 | 400 | | V/μs |
| e _n | Equivalent Input Voltage Noise R _S = 50Ω | | | | $\frac{nV}{\sqrt{Hz}}$ |
| | f _o = 1kHz f _o = 10kHz f _o = 100kHz f _o = 1MHz | | 20 18.2 18.1 18.2 | | |
| K _{ov} | Overshoot V _{in} = ± 1V, A _{VCL} = 2, R _L = 100Ω, C _L = 15pF | | 15 | | % |
| t _s | Settling Time 0.1% - (note 1) V _{in} = ± 1V, A _{VCL} = -1 | | 60 | | ns |
| t _r , t _f | Rise and Fall Time - (note 1) V _{in} = ±100mV, A _{VCL} = 2 | | 2 | | ns |
| t _d | Delay Time - (note 1) V _{in} = ±100mV, A _{VCL} = 2 | | 2 | | ns |
| ∅ _m | Phase Margin A _{VM} = 2, R _L = 100Ω, C _L = 15pF | | 45 | | Degrees |
| THD | Total Harmonic Distortion A _{VCL} = 10, f = 1KHz, V _o = ± 2.5V, no load | | 0.02 | | % |
| FPB | Full Power Bandwidth - (note 2) V _o = 5V _{pp} , R _L = 100Ω V _o = 2V _{pp} , R _L = 100Ω | | 26 64 | | MHz |

Note 1: See test waveform figure**Note 2:** Full power bandwidth = $\frac{SR}{\pi V_{opp}}$

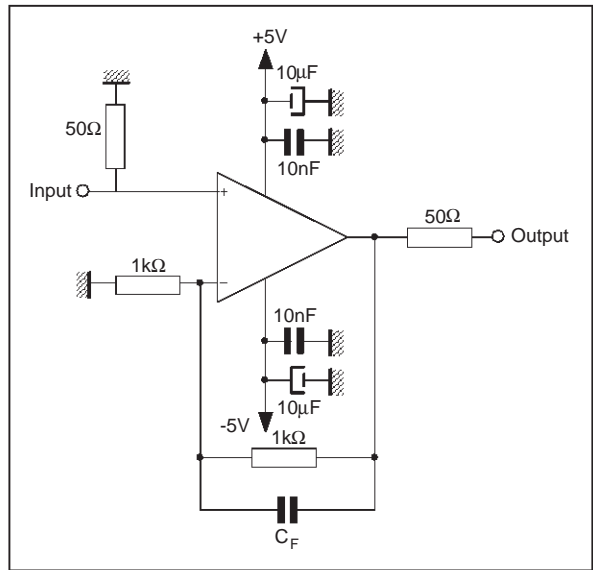
321-04-TBL

TEST WAVEFORM



321-04.EPS

EVALUATION CIRCUIT



321-05.EPS

PRINTED CIRCUIT LAYOUT

As for any high frequency device, a few rules must be observed when designing the PCB to get the best performances from this high speed op amp.

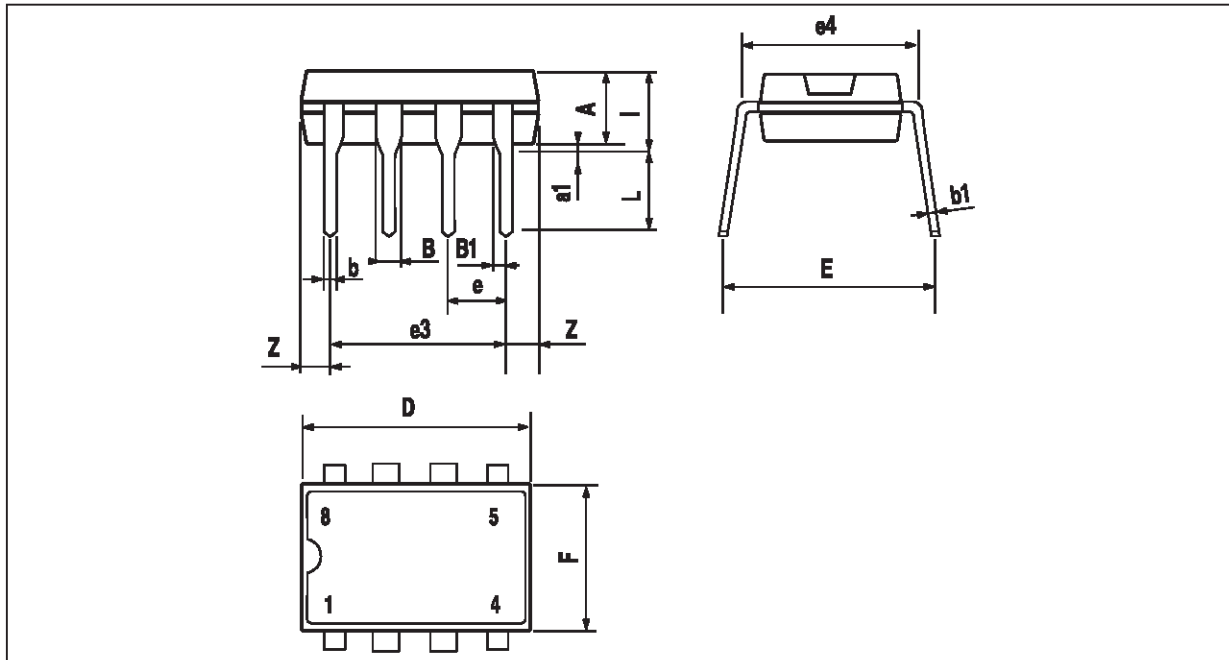
From the most to the least important points :

- Each power supply lead has to be bypassed to ground with a 10nF ceramic capacitor very close to the device and a 10μF tantalum capacitor.
- To provide low inductance and low resistance common return, use a ground plane or common point return for power and signal.
- All leads must be wide and as short as possible especially for op amp inputs. This is in order to decrease parasitic capacitance and

inductance.

- Use small resistor values to decrease time constant with parasitic capacitance.
- Choose component sizes as small as possible (SMD).
- On output, decrease capacitor load so as to avoid circuit stability being degraded which may cause oscillation. One can also add a serial resistor in order to minimise its influence.
- One can add in parallel with feedback resistor a few pF ceramic capacitor C_F adjusted to optimize the settling time.

PACKAGE MECHANICAL DATA
8 PINS - PLASTIC DIP

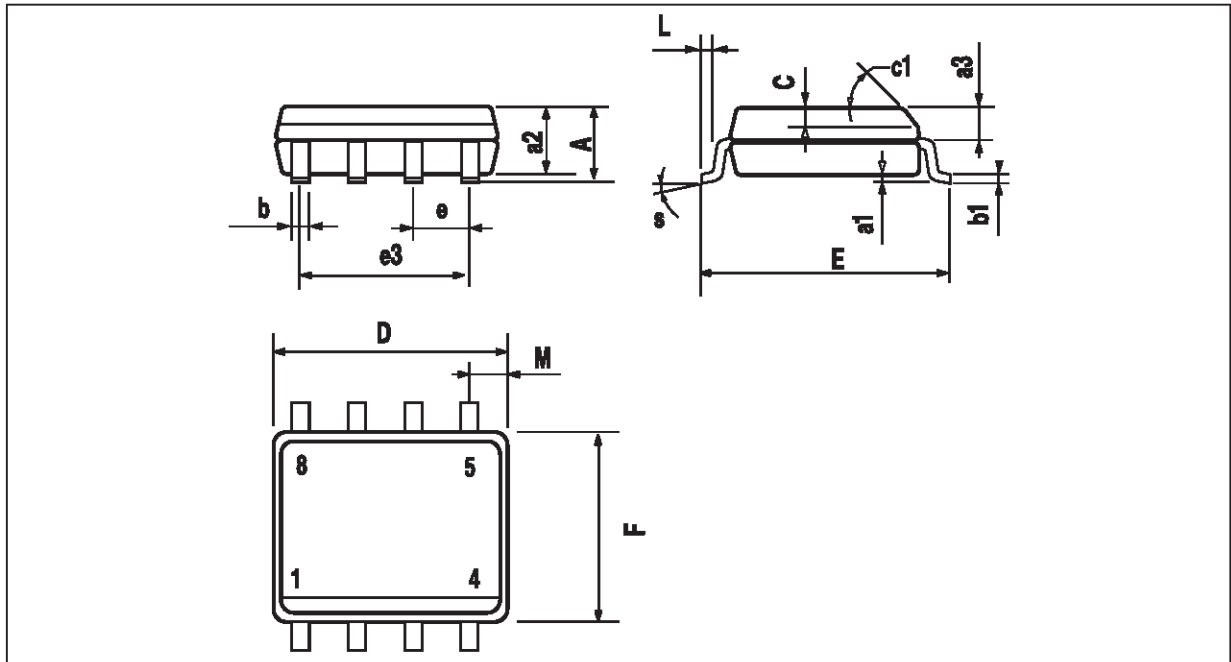


PM-DIP8.EPS

| Dimensions | Millimeters | | | Inches | | |
|------------|-------------|------|-------|--------|-------|-------|
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | | 3.32 | | | 0.131 | |
| a1 | 0.51 | | | 0.020 | | |
| B | 1.15 | | 1.65 | 0.045 | | 0.065 |
| b | 0.356 | | 0.55 | 0.014 | | 0.022 |
| b1 | 0.204 | | 0.304 | 0.008 | | 0.012 |
| D | | | 10.92 | | | 0.430 |
| E | 7.95 | | 9.75 | 0.313 | | 0.384 |
| e | | 2.54 | | | 0.100 | |
| e3 | | 7.62 | | | 0.300 | |
| e4 | | 7.62 | | | 0.300 | |
| F | | | 6.6 | | | 0.260 |
| i | | | 5.08 | | | 0.200 |
| L | 3.18 | | 3.81 | 0.125 | | 0.150 |
| Z | | | 1.52 | | | 0.060 |

DIP8.TBL

PACKAGE MECHANICAL DATA
8 PINS - PLASTIC MICROPACKAGE (SO)



PM-SO8.EPS

| Dimensions | Millimeters | | | Inches | | |
|------------|-------------|------|------|--------|-------|-------|
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | | | 1.75 | | | 0.069 |
| a1 | 0.1 | | 0.25 | 0.004 | | 0.010 |
| a2 | | | 1.65 | | | 0.065 |
| a3 | 0.65 | | 0.85 | 0.026 | | 0.033 |
| b | 0.35 | | 0.48 | 0.014 | | 0.019 |
| b1 | 0.19 | | 0.25 | 0.007 | | 0.010 |
| C | 0.25 | | 0.5 | 0.010 | | 0.020 |
| c1 | 45° (typ.) | | | | | |
| D | 4.8 | | 5.0 | 0.189 | | 0.197 |
| E | 5.8 | | 6.2 | 0.228 | | 0.244 |
| e | | 1.27 | | | 0.050 | |
| e3 | | 3.81 | | | 0.150 | |
| F | 3.8 | | 4.0 | 0.150 | | 0.157 |
| L | 0.4 | | 1.27 | 0.016 | | 0.050 |
| M | | | 0.6 | | | 0.024 |
| S | 8° (max.) | | | | | |

SO8.TBL

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